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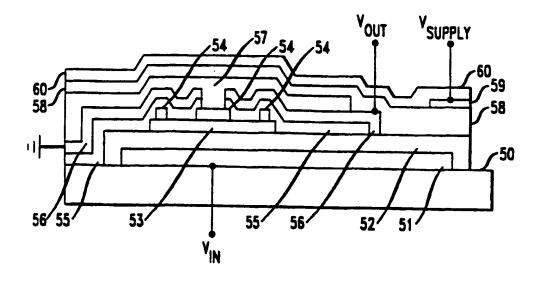
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- (54) Circuit comprising complementary thin film transistors
- (57) In preferred embodiments of the invention, the n-channel inorganic TFTs have an amorphous Si active layer (53), and the p-channel organic TFTs have α -hexathienylene (α 6T) active layer (58). Complementary

inverters according to the invention are disclosed, as is an exemplary processing sequence that can be used to manufacture integrated complementary inverters and other complementary circuits according to the invention.

FIG. 9



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EUROPEAN SEARCH REPORT

EP 97 30 0063

| | DOCUMENTS CONSIDE | HED TO BE HELEVANT | | | |
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| | THE HAGUE | 16 February 1998 | s Kä | inigstein, C | |
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